



A Product Line of Diodes Incorporated



ZXTP19020DZ

20V PNP HIGH GAIN TRANSISTOR IN SOT89

Features

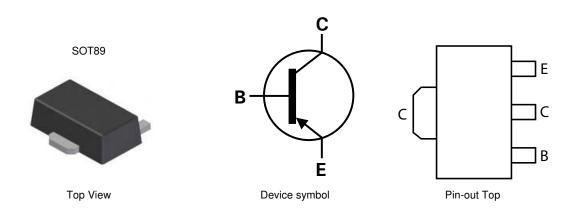
- BV_{CEO} > -20V
- High current capability Max Continuous Current I_C = -6A
- Low saturation voltage V_{CE(sat)} < -47mV @ I_C = -1A
- R_{CE(sat)} = 28mΩ
- P_D = 2.4W
- Complementary part number ZXTN19020DZ
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free, "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT89
- Moisture Sensitivity: Level 1 per J-STD-020
- UL Flammability Rating 94V-0
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)

Application

- Power disconnect switch
- Battery chargers
- High side drivers
- Motor drive



Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP19020DZTA	1M1	7	12	1,000

1. No purposefully added lead.

2. Halogen and Antimony Free. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

3. For packaging details, go to our website at http://www.diodes.com

Marking Information

Notes:







Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{ECO}	-4	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current (Note 6)	Ic	-6	A
Base current	IB	-1	A
Peak Pulse Current	I _{CM}	-15	A

Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	PD	1.1	W
Linear derating factor		8.8	mW/°C
Power Dissipation (Note 5) Linear derating factor	PD	1.8 14.4	W mW/°C
Power Dissipation (Note 6) Linear derating factor	PD	2.4 19.2	W mW/°C
Power Dissipation (Note 7) Linear derating factor	PD	4.46 35.7	W mW/°C
Power Dissipation (Note 8) Linear derating factor	PD	26.7 213	W mW/°C
Thermal Resistance, Junction to Ambient (Note 4)	R _{0JA}	117	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	68	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	51	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JA}	117	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R _{θJL}	4.69	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

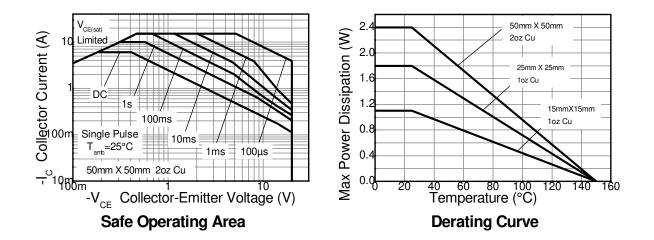
Notes:

4. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions. 5. Mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

6. Mounted on 50mm x 50mm x 0.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.

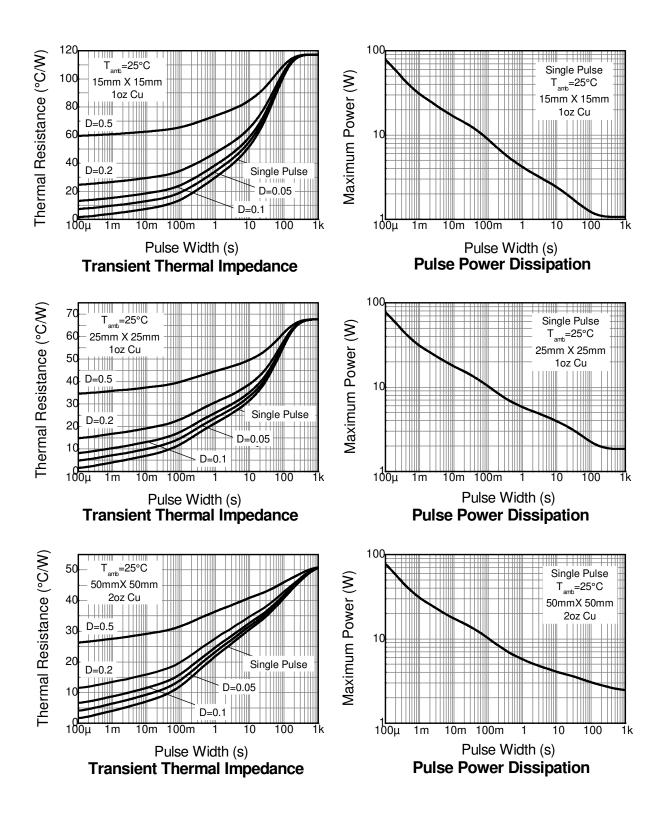
7. As note 6 above measured at t<5 seconds. 8. Junction to case (collector tab). Typical

Thermal Characteristics





Thermal Characteristics (- Continued)





Electrical Characteristics @T_A = 25°C unless otherwise specified

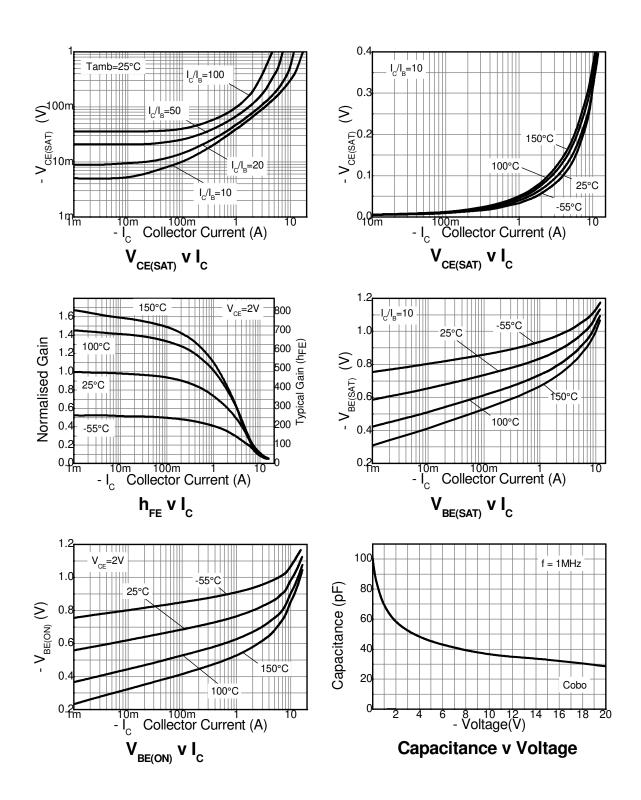
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-25	-55	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Notes 9)	BV _{CEO}	-20	-50	-	V	$I_{\rm C} = -10 \mathrm{mA}$
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECX}	-4	-8.6	-	V	$I_E = -100\mu A$, $R_{BC} < 1k\Omega$ or 0.25V > V _{BC} > -0.25V
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECO}	-4	-8.6	-	V	I _E = -100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.2	-	V	I _E = -100μA
Collector Cutoff Current	1	-	< -1	-50	~ ^	V _{CB} = -25V
Collector Cuton Current	ICBO	-	-	-500	nA	$V_{CB} = -25V, T_A = 100^{\circ}C$
Emitter Cutoff Current	I _{EBO}	-	< -1	-50	nA	V _{EB} = -5.6V
		300	450	900		$I_{C} = -100 \text{mA}, V_{CE} = -2 \text{V}$
DC current transfer Static ratio (Notes 9)	h	200	290	-	_	$I_{C} = -2A, V_{CE} = -2V$
DC current transfer Static ratio (Notes 9)	h _{FE}	65	110	-		$I_{C} = -6A, V_{CE} = -2V$
		-	25	-		$I_{C} = -15A, V_{CE} = -2V$
	V _{CE(sat)}	-	-40	-47	mV	$I_{C} = -1A, I_{B} = -100mA$
Collector-Emitter Saturation Voltage (Notes 9)		-	-100	-130		$I_{C} = -1A, I_{B} = -10mA$
Collector-Emitter Saturation Voltage (Notes 9)		-	-115	-145		$I_{C} = -2A, I_{B} = -40mA$
		-	-225	-275		$I_{C} = -6A, I_{B} = -300mA$
Base-Emitter Saturation Voltage (Notes 9)	V _{BE(sat)}	-	-1000	-1100	mV	$I_{\rm C} = -6A, I_{\rm B} = -300 {\rm mA}$
Base-Emitter Turn-on Voltage (Notes 9)	V _{BE(on)}	-	-865	-1000	mV	$I_{C} = -6A, V_{CE} = -2V$
Transitional Frequency (Notes 9)	f _T	-	176	-	MHz	I _C = -50mA, V _{CE} = -10V, f = 50MHz
Input Capacitance	Cibo	-	-	400	pF	V _{EB} = -0.5V, f = 1MHz
Output capacitance	C _{obo}	-	36	45	pF	$V_{CB} = -10V, f = 1MHz$
Delay time	t _d	-	23	-	ns	
Rise time	tr	-	18.4	-	ns	$V_{CC} = -10V, I_{C} = -1A,$
Storage time	ts	-	266	-	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Fall time	t _f	-	49.6	-	ns	

Notes: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

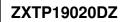




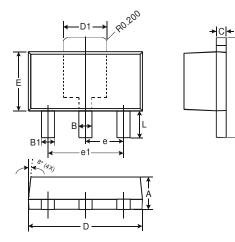
Typical Electrical Characteristics





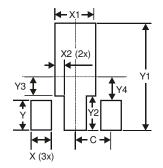


Package Outline Dimensions



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35 0.43			
D	4.40	4.60		
D1	1.52	1.83		
ш	2.29	2.60		
е	1.50 Typ			
e1	3.00 Typ			
Н	3.94 4.25			
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500



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